5V ECL Differential Data and Clock D Flip-Flop

The MC10EL/100EL52 is a differential data, differential clock D flip-flop with reset. The device is functionally equivalent to the E452 device with higher performance capabilities. With propagation delays and output transition times significantly faster than the E452, the EL52 is ideally suited for those applications which require the ultimate in AC performance.

Data enters the master portion of the flip-flop when the clock is LOW and is transferred to the slave, and thus the outputs, upon a positive transition of the clock. The differential clock inputs of the EL52 allow the device to also be used as a negative edge triggered device.

The EL52 employs input clamping circuitry so that under open input conditions (pulled down to V_{EE}) the outputs of the device will remain stable

The 100 Series contains temperature compensation.

- 365 ps Propagation Delay
- 2.0 GHz Toggle Frequency
- ESD Protection: > 1 KV HBM, > 100 V MM
- PECL Mode Operating Range: V_{CC}= 4.2 V to 5.7 V with V_{EE}= 0 V
- NECL Mode Operating Range: V_{CC}= 0 V with V_{EE}= -4.2 V to -5.7 V
- Internal Input Pulldown Resistors on D and CLK
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
 For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 48 devices



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MARKING DIAGRAMS*









CASE 751

TSSOP-8 DT SUFFIX CASE 948R





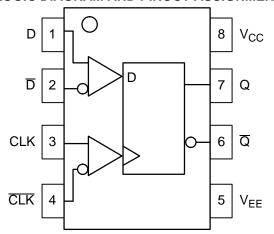
 $\begin{array}{lll} H = MC10 & L = Wafer Lot \\ K = MC100 & Y = Year \\ A = Assembly Location & W = Work Week \end{array}$

ORDERING INFORMATION

Device	Package	Shipping			
MC10EL52D	SO-8	98 Units/Rail			
MC10EL52DR2	SO-8	2500 Tape & Reel			
MC100EL52D	SO-8	98 Units/Rail			
MC100EL52DR2	SO-8	2500 Tape & Reel			
MC10EL52DT	TSSOP-8	98 Units/Rail			
MC10EL52DTR2	TSSOP-8	2500 Tape & Reel			
MC100EL52DT	TSSOP-8	98 Units/Rail			
MC100EL52DTR2	TSSOP-8	2500 Tape & Reel			

^{*}For additional information, see Application Note AND8002/D

LOGIC DIAGRAM AND PINOUT ASSIGNMENT



TRUTH TABLE

D*	CLK*	Q
L H	Z Z	LH

Z = LOW to HIGH Transition

PIN DESCRIPTION

PIN	FUNCTION
D, \overline{D}	ECL Data Input
CLK, CLK	ECL Clock Input
Q, Q	ECL Data Output
V _{CC}	Positive Supply
V _{EE}	Negative Supply

MAXIMUM RATINGS (Note 1.)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8	V
V _{EE}	NECL Mode Power Supply	V _{CC} = 0 V		-8	V
V _i	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$\begin{aligned} & V_{I} \leq V_{CC} \\ & V_{I} \geq V_{EE} \end{aligned}$	6 -6	V V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
TA	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W
θЈС	Thermal Resistance (Junction to Case)	std bd	8 SOIC	41 to 44	°C/W
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W
θ_{JC}	Thermal Resistance (Junction to Case)	std bd	8 TSSOP	41 to 44 ± 5%	°C/W
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

^{1.} Maximum Ratings are those values beyond which device damage may occur.

^{*} Pin will default low when left open.

10EL SERIES PECL DC CHARACTERISTICS V_{CC} = 5.0 V; V_{EE} = 0.0 V (Note 1.)

			-40°C 25°C		85°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		21	25		21	25		21	25	mA
V _{OH}	Output HIGH Voltage (Note 2.)		4010	4110	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 2.)	3050	3200	3350	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage (Single Ended)	3770		4110	3870		4190	3940		4280	mV
V _{IL}	Input LOW Voltage (Single Ended)	3050		3500	3050		3520	3050		3555	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 3.) D CLK	3.4 2.5		4.6 4.4	3.4 2.5		4.6 4.4	3.4 2.5		4.6 4.4	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.3			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 1. Input and output parameters vary 1:1 with V_{CC}.
 - V_{EE} can vary +0.25 V / -0.5 V for +25°C and +85°C. or V_{EE} can vary +0.06 V / -0.5 V for -40°C.
- 2. Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.
- 3. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP}min and 1 V.

10EL SERIES NECL DC CHARACTERISTICS V_{CC} = 0.0 V; V_{EE} = -5.0 V (Note 1.)

			-40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		21	25		21	25		21	25	mA
V _{OH}	Output HIGH Voltage (Note 2.)	-1080	-990	-890	-980	-895	-810	-910	-815	-720	mV
V _{OL}	Output LOW Voltage (Note 2.)	-1950	-1800	-1650	-1950	-1790	-1630	-1950	-1773	-1595	mV
V _{IH}	Input HIGH Voltage (Single Ended)	-1230		-890	-1130		-810	-1060		-720	mV
V _{IL}	Input LOW Voltage (Single Ended)	-1950		-1500	-1950		-1480	-1950		-1445	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 3.) D CLK	-1.6 -2.5		-0.4 -0.6	-1.6 -2.5		-0.4 -0.6	-1.6 -2.5		-0.4 -0.6	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.3			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 1. Input and output parameters vary 1:1 with V_{CC}.
 - V_{EE} can vary +0.25 V / -0.5 V for +25°C and +85°C. or V_{EE} can vary +0.06 V / -0.5 V for -40°C.
- 2. Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.
- 3. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP}min and 1 V.

100EL SERIES PECL DC CHARACTERISTICS V_{CC} = 5.0 V; V_{EE} = 0.0 V (Note 1.)

			–40°C		25°C		85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		21	25		21	25		24	29	mA
V _{OH}	Output HIGH Voltage (Note 2.)		3995	4120	3975	4045	4120	3975	4050	4120	mV
V _{OL}	Output LOW Voltage (Note 2.)	3170	3305	3445	3190	3295	3380	3190	3295	3380	mV
V _{IH}	Input HIGH Voltage (Single Ended)	3835		4120	3835		4120	3835		4120	mV
V_{IL}	Input LOW Voltage (Single Ended)	3190		3525	3190		3525	3190		3525	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 3.) D CLK	2.6 2.5		4.6 4.2	2.6 2.5		4.6 4.2	2.6 2.5		4.6 4.2	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.8 V / -0.5 V.
- 2. Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.
- 3. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP}min and 1 V.

100EL SERIES NECL DC CHARACTERISTICS V_{CC} = 0.0 V; V_{EE} = -5.0 V (Note 1.)

			-40°C 25°C		85°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		21	25		21	25		24	29	mA
V _{OH}	Output HIGH Voltage (Note 2.)	-1085	-1005	-880	-1025	-955	-880	-1025	-955	-880	mV
V _{OL}	Output LOW Voltage (Note 2.)	-1830	-1695	-1555	-1810	-1705	-1620	-1810	-1705	-1620	mV
V _{IH}	Input HIGH Voltage (Single Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V _{IL}	Input LOW Voltage (Single Ended)	-1810		-1475	-1810		-1475	-1810		-1475	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 3.) D CLK	-2.4 -2.5		-0.4 -0.8	-2.4 -2.5		-0.4 -0.8	-2.4 -2.5		-0.4 -0.8	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 1. Input and output parameters vary 1:1 with V_{CC}. $\dot{\rm V}_{EE}$ can vary +0.8 V / –0.5 V.
- 2. Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.
- 3. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP}min and 1 V.

AC CHARACTERISTICS V_{CC} = 5.0 V; V_{EE} = 0.0 V or V_{CC} = 0.0 V; V_{EE} = -5.0 V (Note 1.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Toggle Frequency	1.8	2.5		2.2	2.8		2.2	2.8		GHz
t _{PLH} t _{PHL}	Propagation Delay to Output CLK	225	335	515	275	365	465	320	410	510	ps
t _S	Setup Time	125	0		125	0		125	0		ps
t _H	Hold Time	150	50		150	50		150	50		ps
t _{PW}	Minimum Pulse Width	400			400			400			ps
V _{PP}	Input Swing (Note 2.)	150		1000	150		1000	150		1000	mV
t _{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t _r t _f	Output Rise/Fall Times Q (20% – 80%)	100	225	350	100	225	350	100	225	350	ps

- 1. 10 Series: V_{EE} can vary +0.25 V / -0.5 V for +25°C and +85°C. or V_{EE} can vary +0.06 V / -0.5 V for -40°C 100 Series: V_{EE} can vary +0.8 V / -0.5 V.
- 2. V_{PP}(min) is minimum input swing for which AC parameters guaranteed. The device has a DC gain of ≈40.

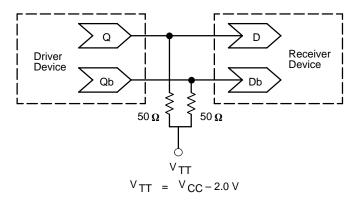


Figure 1. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1404 – ECLinPS Circuit Performance at Non–Standard V_{IH} Levels

AN1405 – ECL Clock Distribution Techniques

AN1406 – Designing with PECL (ECL at +5.0 V)

AN1503 - ECLinPS I/O SPICE Modeling Kit

AN1504 – Metastability and the ECLinPS Family

AN1560 – Low Voltage ECLinPS SPICE Modeling Kit

AN1568 – Interfacing Between LVDS and ECL

AN1596 – ECLinPS Lite Translator ELT Family SPICE I/O Model Kit

AN1650 – Using Wire–OR Ties in ECLinPS Designs

AN1672 – The ECL Translator Guide

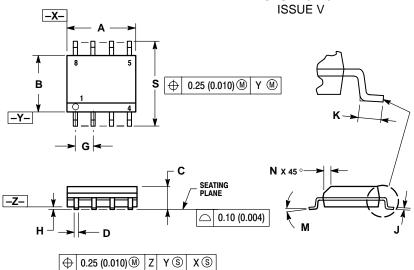
AND8001 - Odd Number Counters Design

AND8002 - Marking and Date Codes

AND8020 - Termination of ECL Logic Devices

PACKAGE DIMENSIONS

SO-8 D SUFFIX PLASTIC SOIC PACKAGE CASE 751-07

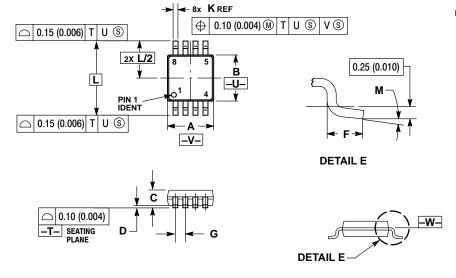


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES		
DIM	MIN	MAX	MIN	MAX		
Α	4.80	5.00	0.189	0.197		
В	3.80	4.00	0.150	0.157		
С	1.35	1.75	0.053	0.069		
D	0.33	0.33 0.51 0.013				
G	1.27	7 BSC	0.050 BSC			
Н	0.10	0.25	0.004	0.010		
J	0.19	0.25	0.007	0.010		
K	0.40	1.27	0.016	0.050		
M	0 °	8 °	0 °	8 °		
N	0.25	0.50	0.010	0.020		
S	5.80	6.20	0.228	0.244		

TSSOP-8 **DT SUFFIX** PLASTIC TSSOP PACKAGE CASE 948R-02 **ISSUE A**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 1. DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD
 FLASH. PROTRUSIONS OR GATE BURRS. MOLD
 FLASH OR GATE BURRS SHALL NOT EXCEED
 0.15 (0.006) PER SIDE.
- 0.13 (0.00) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE
 INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL NOT
 EXCEED 0.25 (0.010) PER SIDE.
- 5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- DIMENSION A AND B ARE TO BE
 DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INCHES								
DIM	MIN	MAX	MIN	MAX							
Α	2.90	3.10	0.114	0.122							
В	2.90	3.10	0.114	0.122							
С	0.80	1.10	0.031	0.043							
D	0.05	0.15	0.002	0.006							
F	0.40	0.70	0.016	0.028							
G	0.65	BSC	0.026	BSC							
K	0.25	0.40	0.010	0.016							
L	4.90	BSC	0.193 BSC								
М	0°	6°	0 °	6°							



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